



60V N-Channel Enhancement Mode MOSFET

Voltage

60 V

Current

11 A

Features

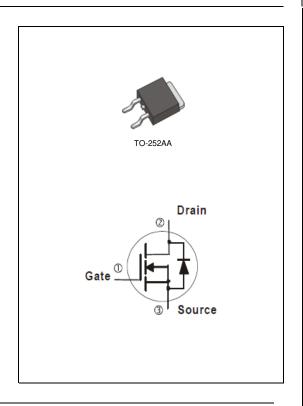
- $R_{DS(ON)}$, V_{GS} @10V, I_{D} @6A<75m Ω
- $R_{DS(ON)}$, V_{GS} @4.5V, I_{D} @3A<90m Ω
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: TO-252AA Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0104 ounces, 0.297grams



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V_{DS}	60	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20		
Continuous Drain Current (Note 4)	T _C =25°C	l _D	11	А	
	T _C =100°C		7		
Pulsed Drain Current (Note 1)	T _C =25°C	I_{DM}	44	<u> </u>	
Power Dissipation	T _C =25°C	PD	30	W	
	T _C =100°C		15	VV	
Continuous Drain Current (Note 4)	T _A =25°C	Ι _D	3.7	^	
	T _A =70°C		2.9	Α	
Power Dissipation	T _A =25°C	Pp	2.4	W	
	T _A =70°C	רם	1.6		
Single Pulse Avalanche Energy (Note 6)		E _{AS}	25	mJ	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~175	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{ heta JC}$	5	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

• Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV _{DSS}	V_{GS} =0V, I_D =250uA	60	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	1	1.8	2.5			
Drain-Source On-State Resistance	R _{DS(on)}	$V_{GS}=10V$, $I_D=6A$	-	53	75	mΩ		
		V_{GS} =4.5V, I_D =3A	-	61	90			
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =60V, V_{GS} =0V	-	-	1	uA		
Gate-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	<u>+</u> 100	nA		
Dynamic (Note 6)								
Total Gate Charge	Q_{g}	V _{DS} =48V, I _D =6A, V _{GS} =10V ^(Note 1,2)	-	9.3	-	nC		
Gate-Source Charge	Q_{gs}		-	2.2	-			
Gate-Drain Charge	Q_{gd}		-	1.9	-			
Input Capacitance	Ciss	V _{DS} =15V, V _{GS} =0V, f=1MHZ	-	509	-	pF		
Output Capacitance	Coss		-	47	-			
Reverse Transfer Capacitance	Crss	I=IIVITZ	-	23	-			
Turn-On Delay Time	td _(on)	$V_{DD}{=}30V,\ I_{D}{=}1A,$ $V_{GS}{=}10V,$ $R_{G}{=}3.3\Omega^{(Note\ 1,2)}$	-	3.2	-			
Turn-On Rise Time	t _r		-	9.7	-	ns		
Turn-Off Delay Time	td _(off)		-	18.5	-			
Turn-Off Fall Time	t _f		-	6.4	-			
Drain-Source Diode								
Maximum Continuous Drain-Source	,				11	Α		
Diode Forward Current	I _S			-	11	^		
Diode Forward Voltage	V_{SD}	I _S =1A, V _{GS} =0V	-	0.75	1	V		

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

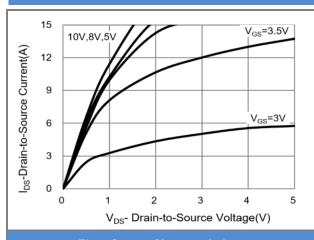


Fig.1 Output Characteristics

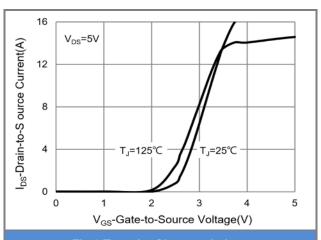


Fig.2 Transfer Characteristics

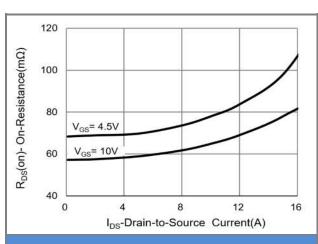


Fig.3 On-Resistance vs. Drain Current

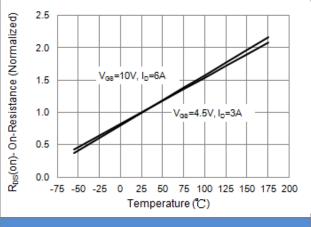
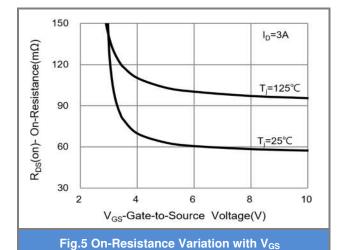


Fig.4 On-Resistance vs. Junction temperature



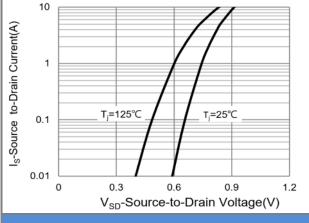


Fig.6 Source-Drain Diode Forward Voltage





TYPICAL CHARACTERISTIC CURVES

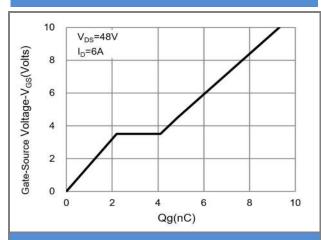


Fig.7 Gate-Charge Characteristics

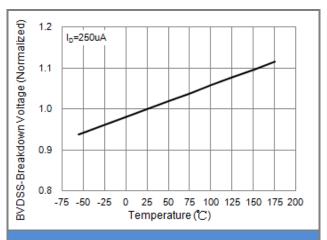


Fig.8 Breakdown Voltage Variation vs. Temperature

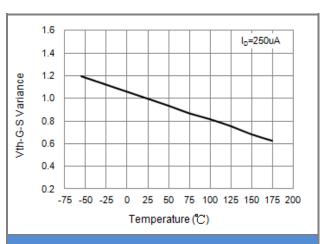


Fig.9 Threshold Voltage Variation with Temperature

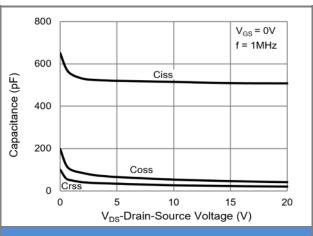


Fig.10 Capacitance vs. Drain-Source Voltage

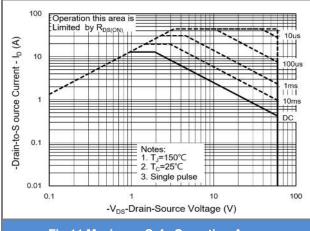


Fig.11 Maximum Safe Operating Area

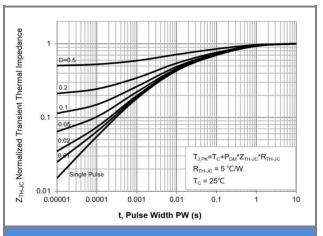


Fig.12 Normalized Transient Thermal Impedance

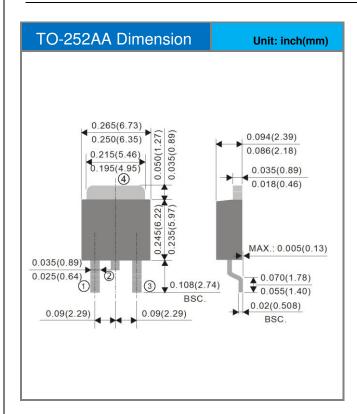


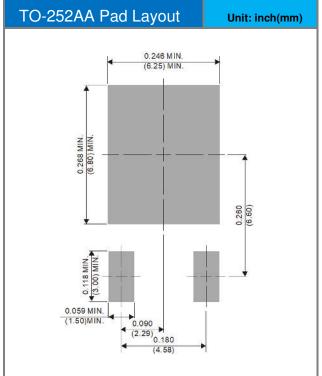


Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version	
PJD11N06A-AU_L2_000A1	TO-252AA	3,000pcs / 13" reel	D11N06A	Halogen free	

Packaging Information & Mounting Pad Layout









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